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Education Information

Doctorate, Sivas Cumhuriyet University, Fen Fakültesi, Fizik Bölümü, Turkey 1995 - 2000

Postgraduate, Sivas Cumhuriyet University, Fen Fakültesi, Fizik Bölümü, Turkey 1992 - 1994

Undergraduate, Sivas Cumhuriyet University, Fen Fakültesi, Fizik Bölümü, Turkey 1985 - 1989

Dissertations

Doctorate, DELTA-KATKILI GaAs YAPILARDA ELEKTRONİK YAPI, Sivas Cumhuriyet Üniversitesi, Fen Fakültesi, Fizik Bölümü, 2000

Postgraduate, FARKLI KATKILANMIŞ YARIİLETKEN MALZEMELERİN ARAYÜZEY POTANSİYEL PROFİLLERİNİN BELİRLENMESİ, Sivas Cumhuriyet Üniversitesi, Fen Fakültesi, Fizik Bölümü, 1994

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